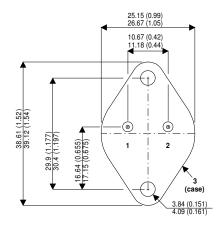
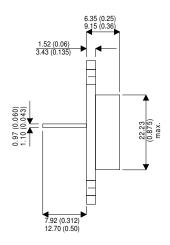




MECHANICAL DATA

Dimensions in mm (inches)





Bipolar NPN Device in a Hermetically Sealed TO3 Metal Package

APPLICATIONS

Intended for High Current Switching Applications.

TO3 (TO204AA)

Pin 1 = Base Pin 2 = Emitter Case = Collector

ABSOLUTE MAXIMUM RATINGS

$T_{CASE} = 25$	$5^{\circ}\mathrm{C}$ unless otherwise state	ed		
V _{CBO}	Collector - Base Voltage	150V		
V_{CEX}	Collector - Emitter Voltage (150V		
$V_{\sf CEO}$	Collector - Emitter Voltage		90V	
V_{EBO}	Emitter – Base Voltage		7V	
Ic	Continuous Collector Current		20A	
I_{B}	Base Current	5A		
P_{tot}	Total Power Dissipation at	$T_{case} = 25 ^{\circ}\text{C}$	140W	
		Derate above 25℃	0.8W/°C	
T _{stg}	Storage Temperature		-65 to 200 ℃	

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2N5038

THERM	AL CHARACTERISTICS	Max.	Unit
R _{th} j-case	Thermal resistance to case	1.25	°C/W

ELECTRICAL CHARACTERISTICS (T_{case}=25 °C unless otherwise stated)

	Parameter Test Conditions		ons	Min.	Тур.	Max.	Unit
h _{FE} *	Forward-current transfer ratio	I _C = 2A	V _{CE} = 5.0V	50		250	
		I _C = 12A		20		100	
V _{CE(sat)} *	Collector to Emitter Saturation Voltage	I _C = 12A	$I_B = 1.2A$			1.0	V
		I _C = 20A	$I_B = 5A$			2.5	
V _{BE(sat)} *	Base to Emitter Saturated Voltage	I _C = 20A	I _B = 5A			3.3	
V _{(BR)CEO} *	Collector to Emitter Breakdown Voltage	I _C = 0.2A		90			
V _{(BR)CEX} *	Collector to Emitter Breakdown Voltage	I _C = 0.2A	$R_{\text{BE}}=100\Omega$	150			
		$V_{BE} = -1.5V$		130			
	Collector Cut-Off Current	V _{CE} = 140V	$V_{BE} = -1.5V$			50	- mA
I _{CEV}		V _{CE} = 100V	$V_{BE} = -1.5V$			10	
		T _{Case} = 150 ℃					
I _{CEO}	Collector Cut-Off Current	V _{CE} = 70V	$I_B = 0$			20	
I _{EBO}	Emitter Cut-Off Current	$V_{EB} = 7V$	1 0			50	
		V _{EB} = 5V	$I_C = 0$			5	
V _{BE} *	Base-Emitter Voltage	$V_{CE} = 5.0V$	I _C = 12A			1.8	V

DYNAMIC CHARACTERISTICS

t _r	Rise Time	$V_{CC} = 30V$	$I_C=12A$			0.5	
ts	Storage Time	1 1 1 2 4				1.5	μs
t _f	Fall Time	I _{B1} =-I _{B2} =1.2A	I _{B1} =-I _{B2} =1.2A			0.5	
C _{ob}	Output Capacitance	I _E = 0	V _{CB} = 10V			500	pF
		f = 1.0MHz				300	þΓ
h _{fe}	Small Signal Current Gain	I _C = 2A	$V_{CE} = 10V$	12			
		f = 5MHz		12			

^{*} Pulse test t_p = 300 μ s, δ < 2%

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